Models

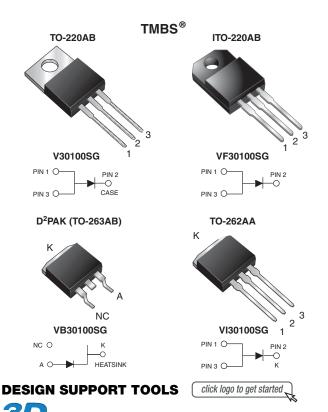
V30100SG-E3, VF30100SG-E3, VB30100SG-E3, VI30100SG-E3

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High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.437 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V_{RRM}	100 V					
I _{FSM}	250 A					
V _F at I _F = 30 A	0.76 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation
- Low thermal resistance

RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30100SG	VF30100SG	VB30100SG	VI30100SG	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	100			V		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30				Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250				Α	
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 90$ mH	E _{AS}	230			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C	I _{RRM}	1.0			Α		
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		٧			
Operating junction and storage temperature range	T _J , T _{STG}	T _J , T _{STG} -40 to +150				°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	$I_R = 10 \text{ mA}$	T _A = 25 °C	V_{BR}	100 (minimum)	-	V	
Instantaneous forward voltage	I _F = 5 A		V _F ⁽¹⁾	0.50	-	V	
	I _F = 10 A	T _A = 25 °C		0.60	-		
	I _F = 30 A			0.92	1.00		
	I _F = 5 A	T _A = 125 °C		0.44	-		
	I _F = 10 A			0.55	-		
	I _F = 30 A			0.76	0.83		
Reverse current	V _R = 70 V	T _A = 25 °C		8.8	-	μΑ	
		T _A = 125 °C	1 (2)	6.5	-	mA	
	V _R = 100 V	T _A = 25 °C	I _R ⁽²⁾	43	350	μΑ	
		T _A = 125 °C		35	35	mA	

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30100SG	VF30100SG	VB30100SG	VI30100SG	UNIT	
Typical thermal resistance	$R_{ heta JC}$	2.0	30	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V30100SG-E3/4W	1.88	4W	50/tube	Tube		
ITO-220AB	VF30100SG-E3/4W	1.74	4W	50/tube	Tube		
TO-263AB	VB30100SG-E3/4W	1.37	4W	50/tube	Tube		
TO-263AB	VB30100SG-E3/8W	1.37	8W	800/reel	Tape and reel		
TO-262AA	VI30100SG-E3/4W	1.45	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

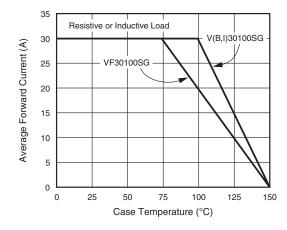


Fig. 1 - Forward Current Derating Curve

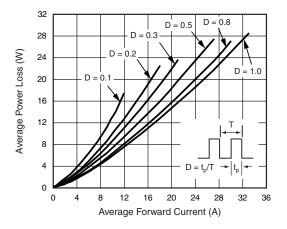


Fig. 2 - Forward Power Loss Characteristics

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

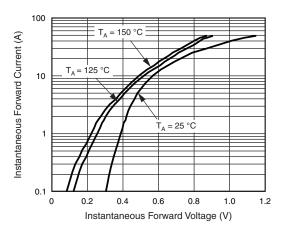


Fig. 3 - Typical Instantaneous Forward Characteristics

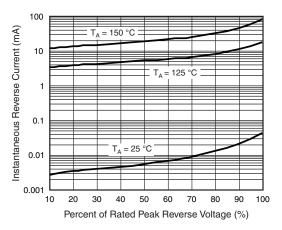


Fig. 4 - Typical Reverse Characteristics

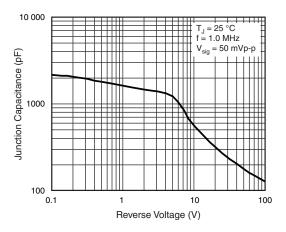


Fig. 5 - Typical Junction Capacitance

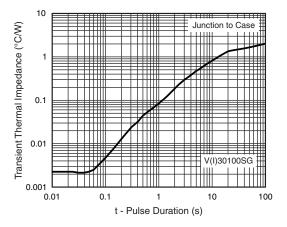


Fig. 6 - Typical Transient Thermal Impedance

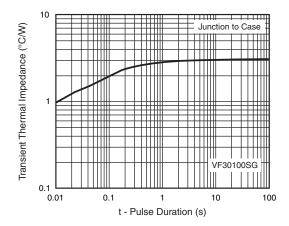


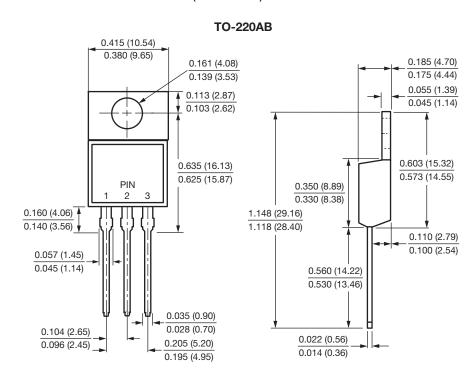
Fig. 7 - Typical Transient Thermal Impedance

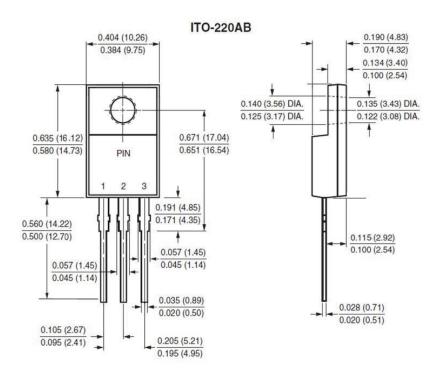
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



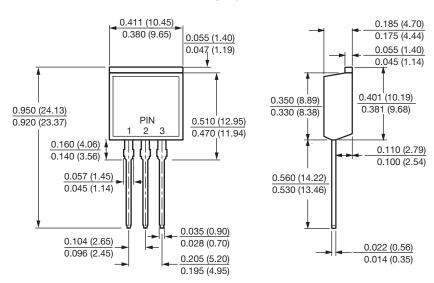


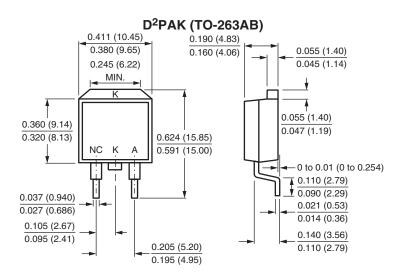
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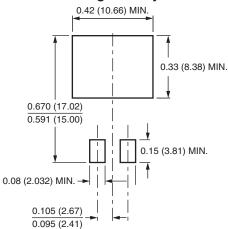
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TO-262AA





Mounting Pad Layout





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